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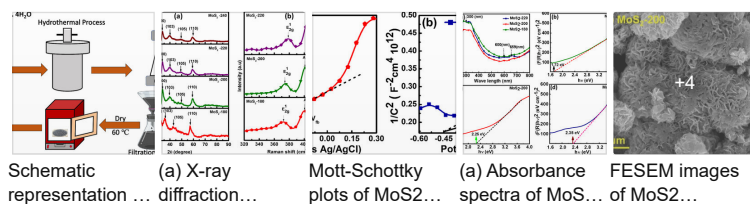
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Abstract and Figures

A simple hydrothermal method was employed to synthesize 3D flower-like MoS₂ nanostructures. The influence of different synthesis temperatures on the structural, electronic, optical and morphological properties of the MoS₂ nanostructures was thoroughly investigated, and the optimal temperature was identified as 220°C. Additionally, we conducted further optimization to determine the most suitable reaction time, which was found to be 24 hours. The characterization of the synthesized MoS₂ nanostructures, employing various techniques such as X-ray diffraction, Raman spectroscopy, Mott-Schottky analysis, UV-Vis-NIR spectroscopy, and field-emission scanning electron microscopy, unveiled well-defined crystallinity, reduced thickness, and uniform morphology, under optimized conditions. Notably, as the temperature increased from 180 to 220°C, the band gap of MoS₂ nanostructures exhibited a notable increase from 1.72 to 2.35 eV. The Mott-Schottky analysis further confirmed our findings, revealing lower values of flat band potential and carrier concentration for the optimized temperature (220°C), indicative of higher crystallinity with fewer defects. These comprehensive findings not only underscore the significant impact of temperature and time on the properties of MoS₂ nanostructures but also hold promising implications for diverse applications, including sensing, energy storage, as well as photocatalysis for hydrogen evolution reactions and organic pollutant degradation.



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Exploring the Influence of Temperature and Time on the Formation and Properties of 3D Flower-Like MoS₂ Nanostructures Synthesized via Hydrothermal Method

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In this study, a simple hydrothermal method was employed to synthesize 3D flower-like MoS₂ nanostructures. The influence of different synthesis temperatures on the structural, electronic, optical and morphological properties of the MoS₂ nanostructures was thoroughly investigated, and the optimal temperature was identified as 220 °C. Additionally, we conducted further optimization to determine the most suitable reaction time, which was found to be 24 h. The characterization of the synthesized MoS₂ nanostructures, employing various techniques such as X-ray diffraction, Raman spectroscopy, Mott-Schottky analysis, UV–vis-NIR spectroscopy and field emission scanning electron microscopy, unveiled well-defined crystallinity, reduced thickness and uniform morphology, under the optimized conditions. Notably, as the temperature increased from 180 °C to 220 °C, the band gap of MoS₂ nanostructures exhibited a notable increase from 1.72 to 2.35 eV. The Mott-Schottky analysis further confirmed our findings, revealing lower values of flat band potential and carrier concentration for the optimized temperature (220 °C), indicative of higher crystallinity with fewer defects. These comprehensive findings not only underscore the significant impact of temperature and time on the properties of MoS₂ nanostructures but also hold promising implications for diverse applications, including sensing, energy storage, as well as photocatalysis for hydrogen evolution reactions and organic pollutant degradation.
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Two-dimensional (2D) transition metal dichalcogenides (TMDs) materials have gained immense research interests owing to their promising electrical, mechanical, optical and chemical properties.^{1–6} These materials, including MoS₂, WS₂, MoSe₂, VS₂, WSe₂ and many more, have shown great potentials for use in various applications, such as electronic devices, gas sensing devices, energy storage devices, hydrogen evolution reactions, solar cells, lubricants, etc.^{2,7–14} MoS₂, as one of the representative members of TMDs, is a well-known two-dimensional (2D) material. Like graphene, MoS₂ consists of a layered structure in which a layer of molybdenum atoms is sandwiched between two layers of hexagonally packed sulphur atoms with strong covalent bonds (S-Mo-S). The layers of MoS₂ are attached together by weak van der Waals forces of attraction.^{15–19} Depending on the stacking sequence and Mo-S coordination, MoS₂ exists in different polytypes, such as 1H, 2H, 1T, and 3R.^{18,20} Among these polytypes, 1H and 2H phases are more stable with trigonal prismatic coordination than other metastable phases of 3R and 1T. The 3R and 1T polytypes of MoS₂ can be easily transferred into the 2H phase via heating. The 2H and 3R phases of MoS₂ possess semiconducting properties and diamagnetic in nature. Moreover, the 1T phase of MoS₂ shows metallic behaviour with paramagnetic nature. Previous studies have demonstrated that the 1T phase has more reactive sites than other phases, which provides better facile route for surface functionalization.^{21,22} Interestingly, owing to their superior semiconducting nature, MoS₂ has become an auspicious material for various application areas, such as optoelectronics, high speed electronics, energy storage, energy conversion and gas sensing as well as in bio sensing.

It has been shown that the synthesis method can play a crucial role not only in synthesizing the nanostructures with desired morphology but also in controlling their physiochemical properties.^{23–27} Various physical as well as chemical methods can be used to synthesize MoS₂ nanostructures.²⁸ Depending on the synthesis method, MoS₂ nanostructures can be formed with different morphologies such as 2D sheets, plates, tubes, ribbons, 3D flower, sphere and so on.^{29–31} Recently, the 3D flower-like morphology of MoS₂ nanostructures has gained enormous interest due to its various practical applications.^{21,32,33} Several physical methods, including sputtering, laser ablation and pulse laser deposition have been used for the synthesis of MoS₂ nanostructures.^{15,30,34–36} Although most of

physical method are very fast, and they involve a lot of complicated procedures and costly instrumentation.²⁸ Moreover, the aggregated tendency of nanostructures synthesized by physical approaches also very high.²⁰ Chemical methods, such as chemical vapour deposition, sol-gel, solvothermal and hydrothermal method, can also be used to synthesize MoS₂ nanostructures.^{37–40} Among chemical methods, the hydrothermal method is the simplest, most economical and versatile method.^{16,30}

Hydrothermal synthesis is a highly promising method for large-scale production of MoS₂ and can be effectively combined with other processes. Remarkably, the unique combination of temperature and pressure in hydrothermal solutions offers an affordable and efficient approach for synthesizing different phases of MoS₂.⁴¹ For instance, Zhang et al. reported the hydrothermal synthesis of 3D flower-like hemispheres consisting of Mo nanosheets using hexadecyltrimethyl ammonium bromide (CTAB) as a surfactant, along with ammonia solution to control the solution pH for various reaction times. However, the shorter duration of 1 h resulted in the presence of impurities due to the surfactant CTAB content.⁴² Another study by Zhang et al. demonstrated the synthesis of nano/micro-spheres of MoS₂ at different temperatures using sodium molybdate dihydrate and thiourea as precursors. While samples synthesized at different temperatures displayed non-uniform morphologies with distinct nanorods and microsphere-like structures, the addition of polyethylene glycol as a surfactant led to more uniform morphology.³¹

Furthermore, Vidhya et al. and Kumar et al. also conducted hydrothermal synthesis to produce MoS₂ nanoflakes and nanoflowers, respectively, at varying temperatures. Interestingly, reaction temperature did not significantly affect the number of MoS₂ layers.^{24,33} In a different study, Yang et al. successfully synthesized MoS₂ nanoflowers under diverse hydrothermal conditions, by adjusting the precursors of Mo, molar ratio of Mo to C, reaction time, reaction temperature, and pH of the solution. The results indicated that MoS₂ nanoflowers exhibited a homogeneous dispersion when prepared with specific conditions, including H₂Mo₇N₆O₂₄ and thiourea precursors, a 1:4 ratio of Mo to C, hydrothermal temperature of 220 °C, an 18 h hydrothermal time and a pH value of 5.²⁹ Lin et al. also explored the possibility of surfactant-assisted hydrothermal preparation to assemble Mo nanospheres consisting of a few layers of nanosheets.³⁹ Moreover, Zhang et al. investigated the influence of the reaction time on the formation of MoS₂ microspheres using hexaammonium

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heptamolybdate tetrahydrate $((\text{NH}_4)_6\text{Mo}_7\text{O}_{24})$ and thiourea as precursors.⁴⁰ Similarly, Thang et al. synthesized MoS_2 nanoflowers with varying reaction times.⁴³ The effect of reaction time on MoS_2 layers was unclear in these studies, leaving a gap in our understanding of how the synthesized nanostructures grow and develop with time. Solving this puzzle is essential to fully harness the exciting properties of MoS_2 for various applications.

In this study, our primary focus was on hydrothermal synthesis, aiming to create 3D flower-like MoS_2 nanostructures. We conducted experiments varying the synthesis temperature between 180 °C and 240 °C to determine the optimal temperature for the best results. Subsequently, we explored the impact of reaction time, ranging from 3 to 48 h, to find the ideal duration for achieving excellent growth and crystallinity of the nanostructures. The outcomes unveiled that a temperature of 220 °C offered the most conducive conditions, resulting in well-defined crystallinity and a unique morphology of MoS_2 nanostructures. Moreover, a thorough analysis of various parameters, such as morphological details, layer thickness, uniformity and crystallinity, strongly suggested that a reaction time of 24 h, paired with a temperature of 220 °C, represented the most optimized conditions for the successful synthesis.

Materials and Method

The chemicals used in this study, including Ammonium molybdate tetrahydrate $((\text{NH}_4)_6\text{Mo}_7\text{O}_{24} \cdot 4\text{H}_2\text{O}$, 99.9%), thiourea $(\text{CH}_4\text{N}_2\text{S}$, 99.9%), DI water and ethanol were purchased from Sigma Aldrich.

Synthesis of MoS_2 .— MoS_2 was synthesized by using ammonium molybdate tetrahydrate $[(\text{NH}_4)_6\text{Mo}_7\text{O}_{24} \cdot 4\text{H}_2\text{O}]$ and thiourea $[\text{CH}_4\text{N}_2\text{S}]$ as precursors for molybdenum and sulphur, respectively, without any further purification. The synthesis process (depicted in Fig. 1) began with the mixing of 1.072 g of ammonium molybdate tetrahydrate and 0.93 g of thiourea in 70 ml of deionized water under vigorous stirring at 800 rpm for an hour at a constant temperature of 30 °C. This resulted in a transparent and homogeneous solution, which was then transferred into a 100 ml Teflon-lined stainless-steel autoclave for heating treatment at different temperatures and times. After completion of the hydrothermal process, the autoclave was allowed to cool down to room temperature naturally. The resulting sample was then washed thoroughly with ethanol and deionized

water by centrifugation at 4000 rpm. Finally, the resultant product was dried at 60 °C for 12 h in a hot air oven. The samples synthesized at temperatures of 180 to 240 °C were labelled as MoS_2 -180, MoS_2 -200, MoS_2 -220 and MoS_2 -240, respectively. Furthermore, to study the influence of reaction time on the MoS_2 nanostructures, different reaction times of 3, 6, 12, 24 and 48 h were used. The synthesized samples with different reaction times of 3, 6, 12, 24, and 48 h were labelled as MS-3, MS-6, MS-12, MS-24, MS-48, respectively.

Material characterizations.—For obtaining the crystallographic information of the synthesized samples, X-ray diffraction (XRD) patterns were recorded using a Rigaku instrument of smart lab with monochromatized Cu K_α radiation ($\lambda = 1.54 \text{ \AA}$) in the 2θ range of 10° – 70° and a scanning rate $5^\circ/\text{min}$. Raman spectra of the synthesized samples were recorded using a Raman spectrometer (Alpha 300/WTIC) with a laser power of 15 mW at an excitation wavelength of 532 nm. The morphological details of the samples were examined using NOVA NanoSEM 450 and 7610 F Plus/JEOL field emission scanning electron microscope (FESEM). The optical properties of the samples were determined using a double beam UV-vis-NIR spectrophotometer (Cary5000, Agilent). Mott-Schottky analysis was carried out to confirm the semiconducting nature of the synthesized materials using Metrohm-Autolab.

Results and Discussion

Influence of temperature.—The crystallographic structure of the hydrothermally synthesized MoS_2 nanostructures was thoroughly analyzed through X-ray diffraction patterns, as depicted in Fig. 2a. Remarkably, all diffraction peaks of the prepared samples perfectly matched the standard JCPDS data (37-1492) for the hexagonal MoS_2 crystal structure, indicating the presence of a pure phase of MoS_2 crystal without any additional peaks.^{28,44,45} Notably, as the reaction temperature increased from 180 °C to 220 °C with a constant moderate reaction time of 24 h, the intensity and sharpness of all diffracted peaks also increased significantly. This phenomenon is attributed to the alignment of atom orientations in a specific direction as the reaction temperature rises, leading to improved crystalline quality and larger crystallite size.²¹ However, the sharpness of the peak corresponding to the (002) plane decreased when

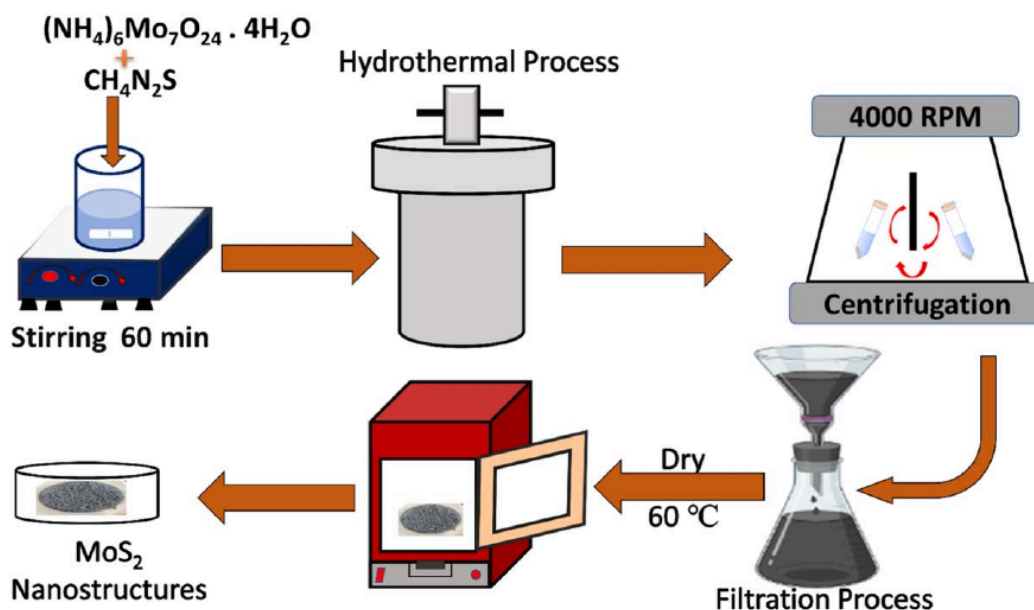


Figure 1. Schematic representation of hydrothermal synthesis of MoS_2 .

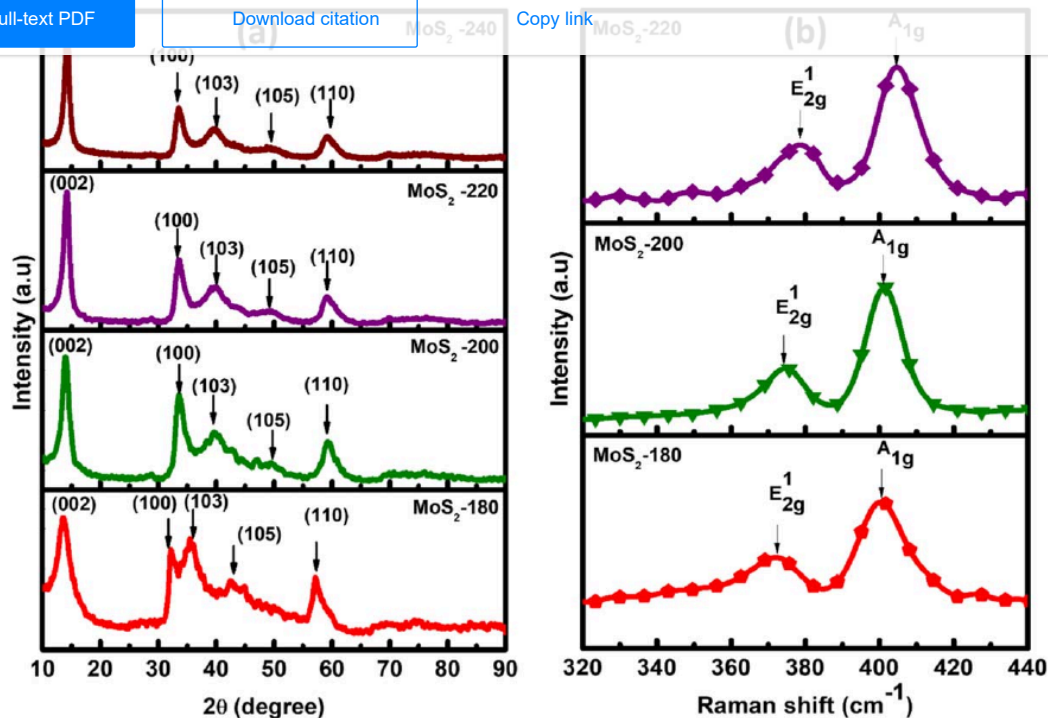


Figure 2. (a) X-ray diffraction patterns of as-synthesized samples at various temperatures ranging from 180 to 240 °C and (b) Raman spectra of samples synthesized at 180, 200, and 220 °C.

Table I. Comparison of diffraction angle (2θ), interlayer spacing (d), crystallite sizes (D), lattice constant (a , b c), microstrain (ϵ) and dislocation density (δ) of as-synthesized MoS₂ samples.

Sample	2θ (hkl)	d (nm)	D (nm)	$a = b$ (Å)	c (Å)	ϵ	δ ($\times 10^{15} \text{ m}^{-2}$)
MoS ₂ -180	13.84° (002)	0.63	4.17	3.13	12.78	0.0087	57.3
MoS ₂ -200	13.80° (002)	0.64	6.23	3.06	12.82	0.0058	25.7
MoS ₂ -220	14.26° (002)	0.62	8.53	3.07	12.45	0.0042	13.7
MoS ₂ -240	14.34° (002)	0.617	7.7	3.06	12.40	0.0047	16.9

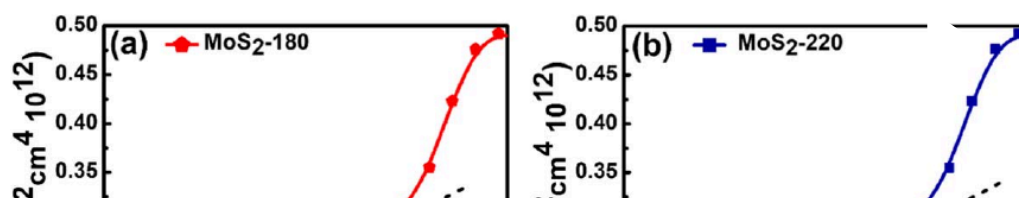
the reaction temperature was further increased from 220 °C to 240 °C. This could be attributed to the bending of MoS₂ nanosheets under faster reaction conditions at higher temperatures, resulting in the introduction of defects and strain effects in the sample.^{46,47}

It was observed that as the reaction temperature increased from 180 °C to 240 °C, the positions of the peaks shifted towards the right side, indicating a decrease in the interplanar spacing of the MoS₂ nanostructures synthesized at higher temperatures.²⁷ Notably, the ratio of peak intensity at 14.26° (I_{002}) to the peak intensity at 33.26° (I_{100}) increased with rising reaction temperature, suggesting that higher temperatures inhibited the lamellar growth and accumulation.²⁸ The strong peak at 14.26°, corresponding to the (002) plane, indicates the well-formed long-range stacking layers along the c -axis in the material.²¹

As the reaction temperature increased from 180 °C to 220 °C, the crystallite size of the materials gradually increased, while both the microstrain and dislocation density decreased. However, with a further temperature increased from 220 °C to 240 °C, the crystallite

size decreased, and both microstrain and dislocation density increased. These changes, as shown in Table I, suggest that the sample synthesized at 220 °C exhibited better crystalline quality due to its larger crystallite size (8.53 nm) and lower microstrain (0.0042) and dislocation density (13.7 m^{-2}). Therefore, we considered 220 °C as the best-optimized temperature and utilized it for further studies.

Raman spectroscopy with a laser wavelength of 532 nm was used to further investigate the number of layers and crystallographic properties of as prepared MoS₂ nanostructures. In the Raman spectra of the MoS₂ samples (as shown in Fig. 2b, we can see two intense peaks at 378 and 404 cm⁻¹. These two peaks are the characteristics peaks of the hexagonal structure of the MoS₂ that arise due to in-plane (E_{2g}^1) and out-of-plane (A_{1g}) vibration modes of MoS₂ respectively.⁴⁸ The presence of these characteristic peaks in all three samples confirms the hexagonal phase of MoS₂ in all the prepared samples. It is clearly seen from the Raman spectra that the E_{2g}^1 and A_{1g} peaks are blue-shifted as the reaction temperature



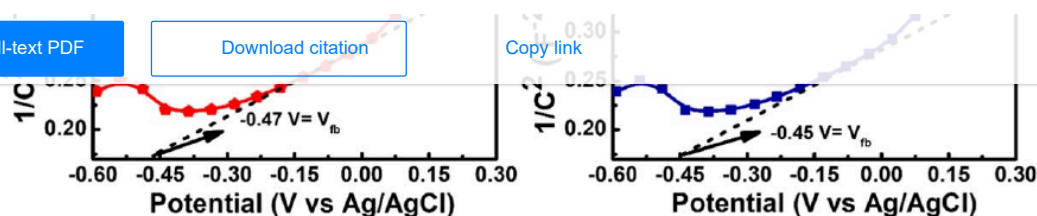


Figure 3. Mott-Schottky plots of MoS₂ samples prepared with 180 and 220 °C temperature.

increases from 180 to 220 °C. This is because of the suppression of interatomic vibration of van der Waals forces that leads to increased force constants with an increase in the number of layers.⁴⁹ It is well established that the difference in the Raman shift of E_{2g}¹ and A_{1g} peaks can be used to determine the number of stacking layers of MoS₂ samples.⁴⁹ From Fig. 2b, we can see that the difference in the position of the E_{2g}¹ and A_{1g} peaks decreases with an increase in temperature, indicating a decrease in the number of MoS₂ layers at higher temperature. Furthermore, E_{2g}¹ is related to the crystalline quality of the samples. Broadening and low intensity of this peak suggest the presence of some defects in the basal plane of MoS₂.²¹ Here, we can see that with increasing hydrothermal temperature, the intensity and sharpness of this peak increases, revealing an improvement in crystalline quality and a reduction in structural defects. This observation is in good agreement with our XRD data. More specially, the lower intensity of the E_{2g}¹ peak than A_{1g} peak suggests the edge-terminated MoS₂ of a few layers in all synthesized samples. Moreover, the intensity ratio of these A_{1g} and E_{2g}¹ vibration modes also provides information about the intrinsic properties of materials.⁵⁰ The sample with a higher intensity ratio can be attributed to lower electron density. As the hydrothermal temperature increases from 180 to 220 °C, the intensity ratio also increases, suggesting a reduction in the electron density of the synthesized samples.⁴⁹ Additionally, the reduction in electron density is attributed to the presence of Mo and S vacancies introduced during the growth process. When S vacancies or Mo vacancies are incorporated into the MoS₂ lattice, some defect energy levels start to develop in the forbidden gap region, which relates to gradually improved energy bands and electron concentration.⁵¹ As shown by the Raman and XRD analysis, the defect density decreases with an increase in the reaction temperature, indicating a decrease in the electron concentration with an increase in the reaction temperature.

To further confirm the carrier concentration at higher temperature, Mott-Schottky analysis was conducted as using an electrochemical workstation with a three-electrode configuration and a 1 M Na₂SO₄ electrolyte solution at room temperature. A silver-silver chloride (Ag/AgCl) electrode served as the reference electrode, while a Pt wire acted as the counter electrode. The MoS₂ samples, mixed with a few drops of an ethanol solution, were applied to the surface of a glassy electrode used as the working electrode. By applying a potential bias, an equilibrium at the interface of the electrolyte and working electrode was established, facilitating the transfer of electrons from the semiconductor electrode to the electrolyte.

Figures 3a–3b illustrates the Mott-Schottky curves for the samples, showing positively sloping characteristics that indicate n-type conductivity of the as-prepared MoS₂ nanostructures.⁵² The flat band potentials were determined by extrapolating the linear portion

Table II. Comparison of flat band potential and carrier concentration of as-prepared samples at different temperature 180 and 220 °C.

Sample	Flat band potential (V)	Carrier concentration (cm ⁻³)
MoS ₂ – 180	–0.47	9.1 × 10 ¹⁹
MoS ₂ – 220	–0.45	7.3 × 10 ¹⁹

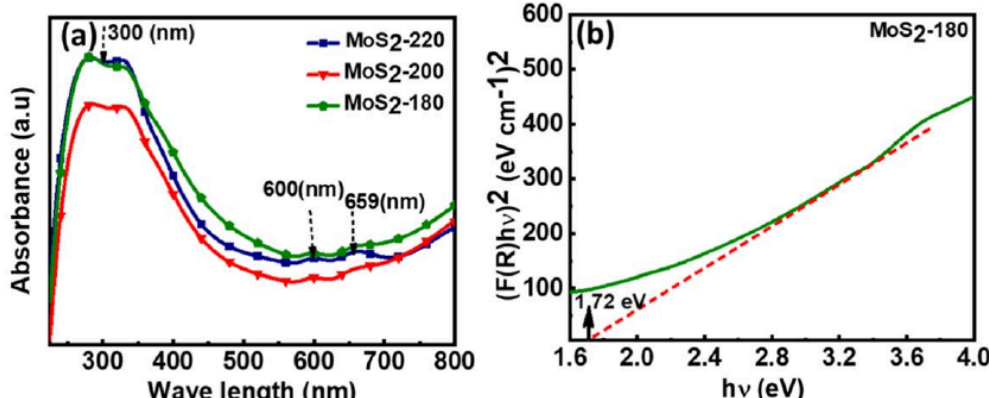
of the Mott-Schottky curve to the X-axis at point 1/C² = 0. The obtained values of the flat band potential were summarized in Table II for MoS₂–180 and MoS₂–220.

The carrier concentration of the synthesized samples was also determined from the slope of the linearly fitted Mott-Schottky curve in the potential region –0.4 to 0.2 V, as shown in Figs. 3a–3b. The carrier concentration (N_D) was calculated using the equation:

$$N_D = \frac{2}{e\epsilon\epsilon_0} \left[\frac{dV}{d(1/C^2)} \right]$$

where N_D is the carrier concentration, ϵ is the dielectric constant of the material, ϵ_0 is the permittivity of free space, e is the electronic charge, and $dV/d(1/C^2)$ is the slope of the Mott-Schottky curve of the as-synthesized samples. The calculated values of carrier concentrations for MoS₂–180 and MoS₂–220 samples were presented in Table II.

The relationship between flat band potentials and carrier concentration in nanostructures is indeed influenced by the presence of defects, particularly sulphur vacancies in MoS₂. As evidenced by the data in Table II, the MoS₂–220 sample exhibited lower values of both carrier concentration and flat band potential compared to the MoS₂–180 sample. This significant difference can be attributed to the presence of lower defects, specifically fewer sulphur vacancies, in the MoS₂–220 sample. In contrast, samples synthesized at lower temperature demonstrated relatively higher carrier concentrations, primarily due to the influence of sulphur vacancies. These vacancies induced during the synthesis process act as traps, capturing electrons in defect-induced energy states, which results in an increase in carrier (electron) concentration.^{53–55} This phenomenon contributes to the higher carrier concentration observed in the MoS₂–180 sample. By combining the data from Table II with the results of XRD and Raman analysis, we can assert that the lower value of flat band potential in the MoS₂–220 sample, synthesized at 220 °C, can be attributed to the lower carrier concentration resulting from enhanced crystalline quality and reduced sulphur vacancies.⁴⁹ Overall, the presence of defects, particularly sulphur vacancies, plays a crucial role in influencing the carrier concentration and, consequently, the flat band potentials in



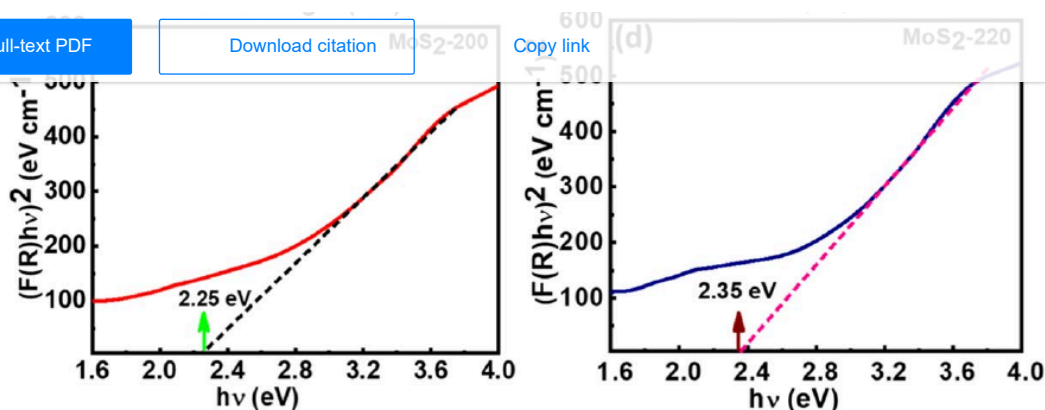


Figure 4. (a) Absorbance spectra of MoS₂ samples prepared at different temperatures. (b) Diffuse Reflectance Spectroscopy (DRS) plot of MoS₂ sample prepared at 180 °C. (c) DRS plot of MoS₂ sample prepared at 200 °C. (d) DRS plot of MoS₂ sample prepared at 220 °C.

MoS₂ nanostructures. The higher crystalline quality and reduced sulphur vacancies in the MoS₂-220 sample contribute to the observed lower carrier concentration and flat band potential, highlighting the importance of defect engineering for optimizing the electronic properties of nanomaterials.^{56–58}

The optical properties of MoS₂ nanostructures synthesized at different temperatures were studied using UV–vis–NIR diffuse reflectance spectroscopy. In the absorbance spectra (Fig. 4a) of the MoS₂ samples, a higher absorbance was observed in the UV region compared to the visible region, with the highest peak observed at around 300 nm. This high absorbance is due to inter-band transition of occupied d_{z^2} orbitals to unoccupied $d_{xy-x^2-y^2}$ and d_{xz-yz} orbitals.⁵⁹ Two exciton peaks were also observed at 600 and 659 nm, which are attributed to direct band gap transition at K-points of the Brillouin zone.^{59,60} It is clearly seen that the appearance of excitonic peaks becomes more intense with an increase in reaction temperature, which is due to the reduction of the number of MoS₂ layers with increasing reaction temperature.³¹

The UV- diffuse reflectance spectra of the as-prepared samples were converted into absorption spectra using Kubelka Munk theory:^{52,61}

$$F(R_{\infty}) = \frac{(1 - R_{\infty})^2}{2R_{\infty}} = \frac{\alpha}{S}$$

$$R_{\infty} = \frac{R_{\text{sample}}}{R_{\text{standrad}}}$$

where $F(R_{\infty})$, α , S , R denote the Kubelka Munk Function, absorption coefficient, scattering coefficient and reflectance,

respectively. The optical band gap of MoS₂ samples synthesized at different temperatures was determined using the theory of optical transition,

$$F(R_{\infty})h\nu = B(h\nu - E_g)^n$$

where $h\nu$ is the energy of the incident photon, B is the constant for the material, n is the electronic transition ($n = 1/2$ for direct allowed transition, $n = 2$ for indirect allowed transition). The Kubelka Munk function was used to determine the value of the absorbance coefficient α from the reflectance spectra of MoS₂ samples. However, for the estimation of the band gap of the material, $F(R_{\infty})$ can be used instead of α .⁵² The curves of $[F(R_{\infty})h\nu]^2$ versus $h\nu$ were plotted and the optical band gap of MoS₂ samples was determined by extrapolation of the linear portion of $[F(R_{\infty})h\nu]^2 = 0$.

In Figs. 4b to 4d, we observed a gradual increase in the band gap of MoS₂ nanostructures from 1.72 to 2.35 eV as the reaction temperature increased from 180 to 220 °C. This trend in the band gap modulation can be attributed to the decrease in the number of MoS₂ layers as the reaction temperature increased, a phenomenon supported by previous studies.^{49,62,63}

The Raman analysis further validated this observation, revealing a decrease in the number of layers as indicated by the position difference of Raman active peaks of MoS₂ from 180 °C to 220 °C. The increase in the band gap of the nanostructures can be attributed to the well-known quantum confinement effect, a key aspect in low-dimensional materials.^{64,65} Quantum confinement restricts the motion of electrons to specific energy levels within the reduced dimensionality of the material. As the MoS₂ transitions from a bulk (3D) structure to a 2D structure, the decrease in the confining dimensionality results in the formation of discrete energy levels,

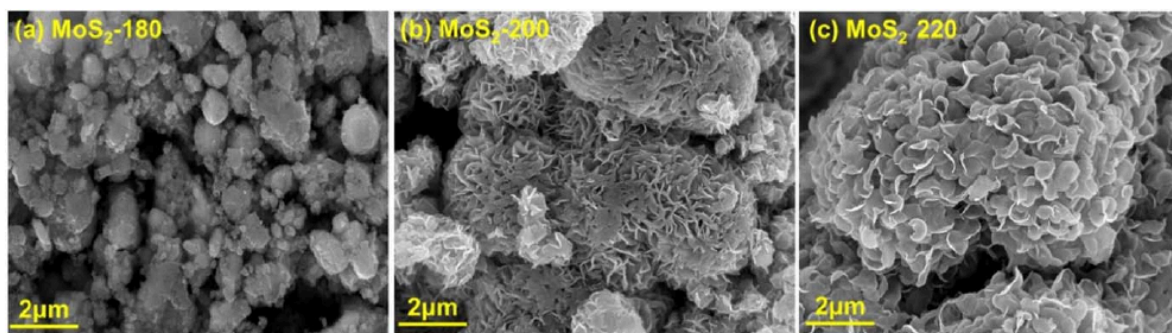
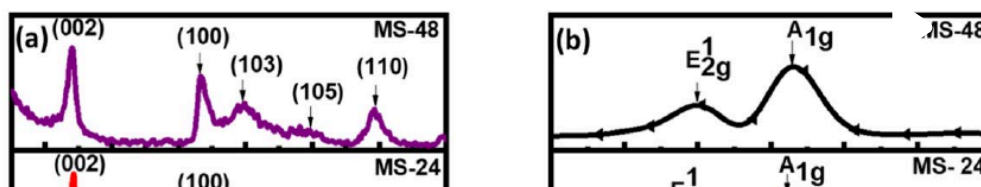


Figure 5. FESEM images of MoS₂ nanostructures synthesized at different temperatures (a) 180 °C (b) 200 °C and (c) 220 °C.



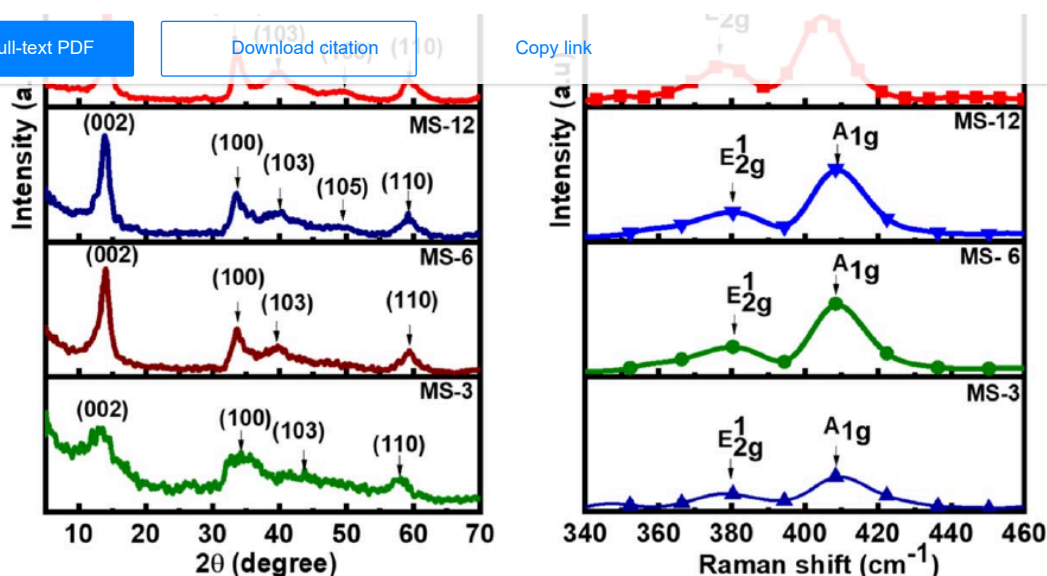


Figure 6. (a) XRD and (b) Raman spectra of MoS₂ samples synthesized at different reaction time of 3 (MS-3), 6 (MS-6), 12 (MS-12), 24 (MS-24) and 48 (MS-48) h.

leading to a splitting of energy levels due to quantum confinement. This energy level splitting ultimately leads to the widening of the band gap in the material. Our findings on the band gap values of various MoS₂ nanostructures are consistent with reported values in the literature, which range from 1.58 to 2.35 eV.^{24,49,53} These findings provide valuable insights into the tunability of the band gap of MoS₂ nanostructures, holding significant implications for their potential applications in various electronic and optoelectronic devices.^{23,42,66}

The morphologies of the as-prepared samples were investigated using a field emission scanning electron microscope (FESEM) and are provided in Fig. 5. The results clearly demonstrate that the surface morphology of the samples can be improved with an increase in reaction temperature. As the reaction temperature increases, the nanoflowers exhibit a more voluminous structure, accompanied by a

noticeable reduction in the thickness of the constituent nanosheets, a trend that is also corroborated by the Raman analysis. It is worth mentioning that the fluffy nature of the nanoflowers can provide more void space, which could be beneficial in many of applications, such as gas sensing and biosensing, energy storage and conversion, photocatalytic activities, etc.^{43,48}

Influence of reaction time.—To investigate the impact of reaction time on the properties of MoS₂ nanostructures, various reaction durations of 3, 6, 12, 24, and 48 h were employed at a consistent reaction temperature of 220 °C, which had been optimized in the preceding section. Figure 6a showcases the X-ray diffraction pattern of MoS₂ samples synthesized under different reaction times: 3 (MS-3), 6 (MS-6), 12 (MS-12), 24 (MS-24), and 48 (MS-48) h. The diffraction peaks of all samples demonstrate the pure MoS₂

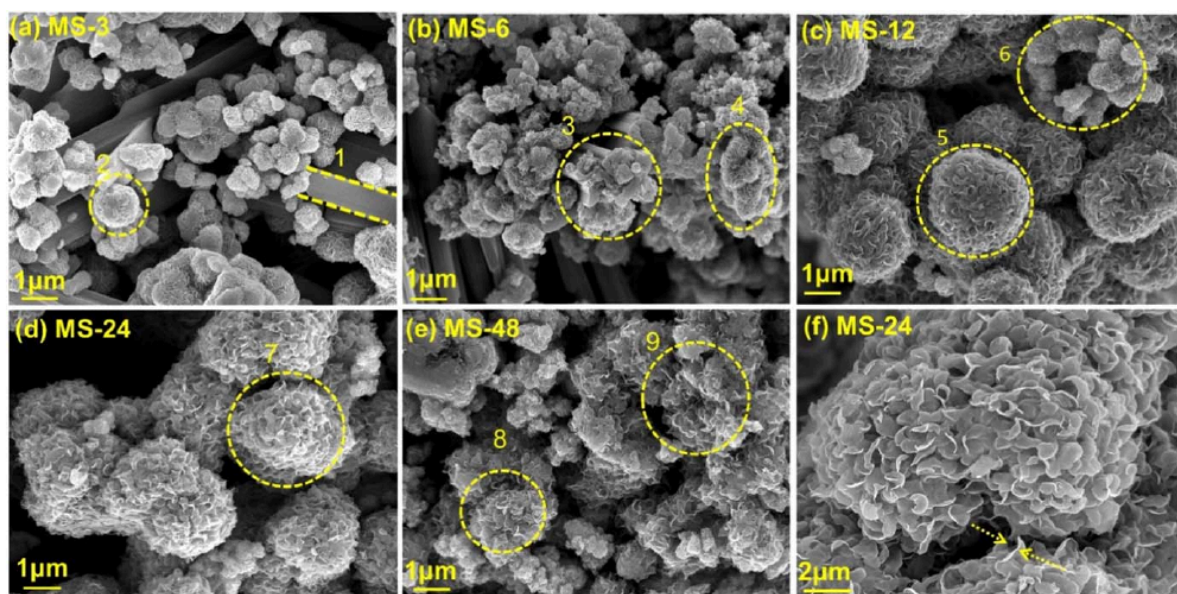


Figure 7. FESEM micrographs of MoS₂ nanostructures prepared with 3 h (a) 6 h (b) 12 h (c) 24 h (d) 48 h (e), (f) 24 h at higher magnification.

Table III. Comparison of diffraction angle (2θ), interlayer spacing (d), crystallite sizes (D), lattice parameters (a , c), microstrain (ϵ) and dislocation density (δ) of as synthesized samples with different time duration.

Sample	2θ (hkl)	d (nm)	D (nm)	a (Å)	c (Å)	ϵ	$\delta (1 \times 10^5/\text{m}^{-2})$
M-3	13.47° (002)	0.657	4.64	3.06	13.13	0.033	46.4

phase and align with JCPDS data (37–1492).^{28,44} The sample synthesized for 3 h (MS-3) displays a low-intensity, broad diffraction peak at 13.47°, corresponding to the (002) plane of the 2H phase of the MoS₂ crystal. The subdued intensity and broadness of this peak can be attributed to a smaller crystallite size. As the reaction time increases, the intensity of this peak augments, indicating an improvement in crystalline quality and the formation of well-stacked layers of MoS₂ nanostructures along the *c*-axis.³³

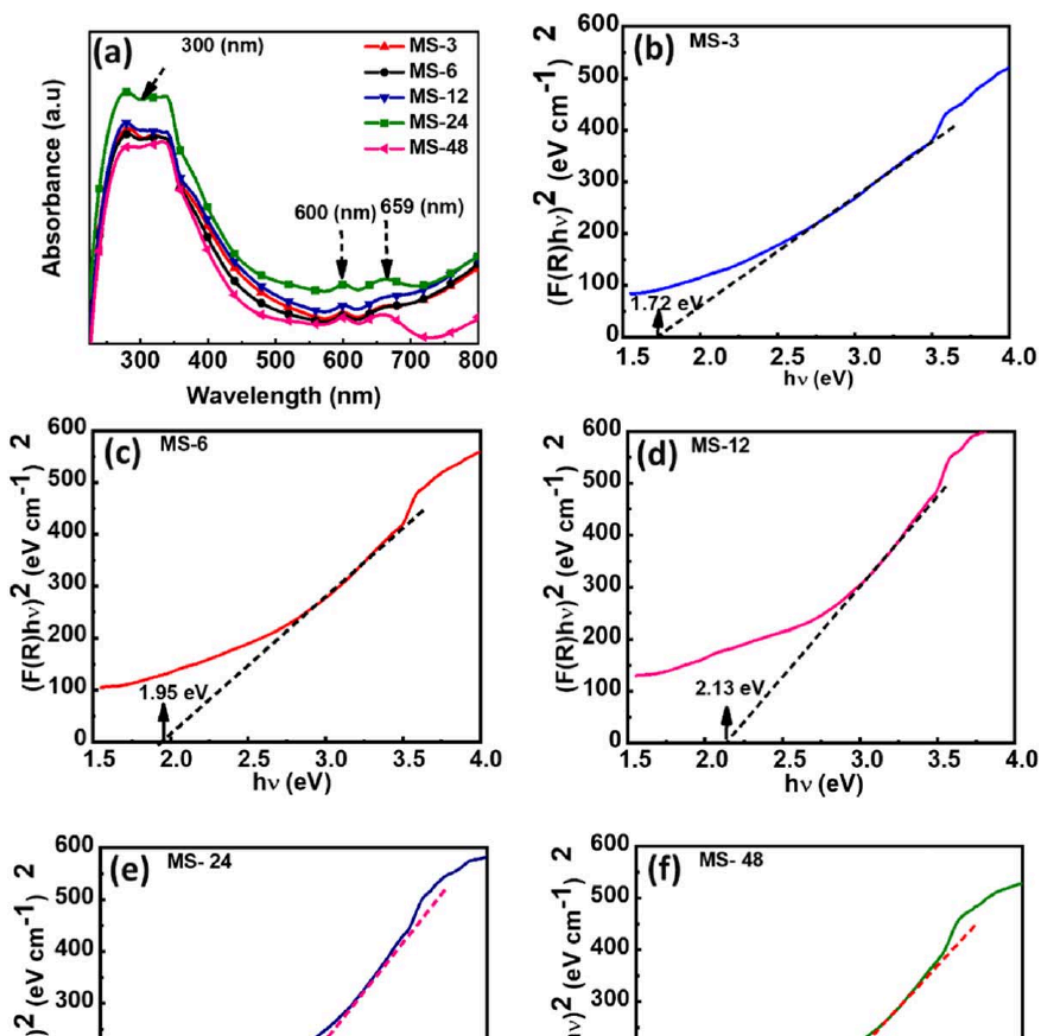
Furthermore, the shift in the peak position of the (002) plane towards a higher angle of 2θ with prolonged reaction time results in a reduced interplanar spacing of samples synthesized for an extended duration, affirming the heightened purity of the synthesized samples.

Table III presents the escalating crystallite size and diminishing interplanar spacing for MoS₂ samples prepared with longer reaction times. The table also provides microstrain and dislocation density calculations derived from XRD data. It is evident from Table III that MoS₂ nanostructures synthesized for 24 h at 220 °C exhibit superior crystallite quality and lower defect density. This favourable outcome can be attributed to the presence of smaller microstrain (0.004) and dislocation density (13.7 m^{-2}) at a reaction temperature of 220 °C for a duration of 24 h.⁴⁹

Furthermore, Raman analysis was employed to investigate the influence of various reaction times on the structural properties of MoS₂ samples. As depicted in Fig. 6b, all the samples prepared with different reaction times exhibited two characteristic peaks of MoS₂ at 378 and 404 cm^{-1} .²¹ As previously discussed, the difference in the E_{2g}^1 and A_{1g} peak positions were utilized to evaluate the number

of MoS₂ layers. The difference in the peaks position with reaction time of 3, 6, 12, 24 and 48 h were found to be 31, 29, 27, 26 and 27 cm^{-1} , respectively. It can be observed that the peaks difference first decreases with an increase in the reaction time from 3 to 24 h, and then it increases as the reaction time increases from 24 to 48 h. This reduction in peaks difference indicates a reduction in MoS₂ layers, as discussed earlier. It is worth noting that the sample prepared with 24 h has a smaller number of layers with better crystalline quality due to a smaller FWHM of E_{2g}^1 which was also confirmed by XRD data.

FESEM images of MoS₂ nanostructures synthesized at different reaction times are presented in Figs. 7a–7f. The images clearly demonstrate that the surface morphology of MoS₂ samples can be significantly modified by varying the reaction time. MoS₂ nanostructures synthesized for shorter reaction times of 3 and 6 h mostly consist of nanorod-like structures, as shown in Fig. 7a, denoted by numeric symbol 1 (dotted line). Some flower-like structures also start to form at the end of the nanorods, as depicted in Fig. 7b and indicated by numeric symbol 3 (dotted circle). These rod-like nanostructures are believed to have occurred due to incomplete dissolution of Mo precursor during the shorter reaction time. As the reaction time is increased from 6 to 12 h, the rod-like nanostructures disappear completely, and some flower-like structures with small petals appear (marked by numeric symbol 6), as shown in Fig. 7c and denoted by numeric symbol 5. Interestingly, flowers with bigger and thinner petals are formed when the synthesis time increases from 12 h to 24 h. The nanosheets become thinner for samples grown for



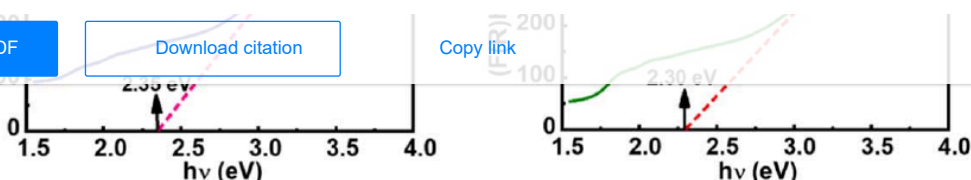


Figure 8. (a) Absorbance and (b-f) diffuse reflectance spectra of MoS₂ samples synthesized with different reaction time.

24 h, as indicated by yellow arrows in Fig. 7f at higher magnification. The increase in nanoflower size is due to the fact that as the reaction time increases, self-assembly of nanosheets also increases. A plausible growth mechanism for the formation of 3D flower-like structures is explained in the Growth Mechanism section of this study. However, the sample prepared for 48 h consists of nanoflowers with non-uniform MoS₂ nanosheets. Hence, when the reaction temperature is prolonged to 48 h, the 3D flowers gradually diminished and disperse into interconnected nanosheets denoted by the yellow circle with numeric symbols 8 and 9 in Fig. 7e.

The UV-vis-NIR absorbance spectra and diffuse reflectance spectroscopy (DRS) plots for band gap calculation of the as-prepared MoS₂ samples are depicted in Fig. 8.

As shown in Fig. 8a, the intensities of excitonic peaks at 600 and 659 nm increase with an increase in reaction time.⁶⁷ This is

attributed to a reduction in the number of MoS₂ layers with an increase in the reaction time, as discussed earlier. Interestingly, the value of the band gap of MoS₂ nanostructures first increases from 1.72 to 2.35 eV as the reaction time increases from 3 to 24 h, but then the value of the band gap decreases as we increase the reaction time from 24 to 48 h. This decrease in the band gap with an increase in the reaction time from 24 to 48 h was attributed to an increase in the number of layers, which was also confirmed by Raman analysis. As discussed previously, the decrease in the number of layers with an increase in the band gap can be attributed to the quantum confinement effect in 2D MoS₂ nanosheets.

Growth mechanism.—Based on various structural and morphological findings, the most possible growth mechanism for 3D flower-like MoS₂ nanostructures formed by the stacking of thin

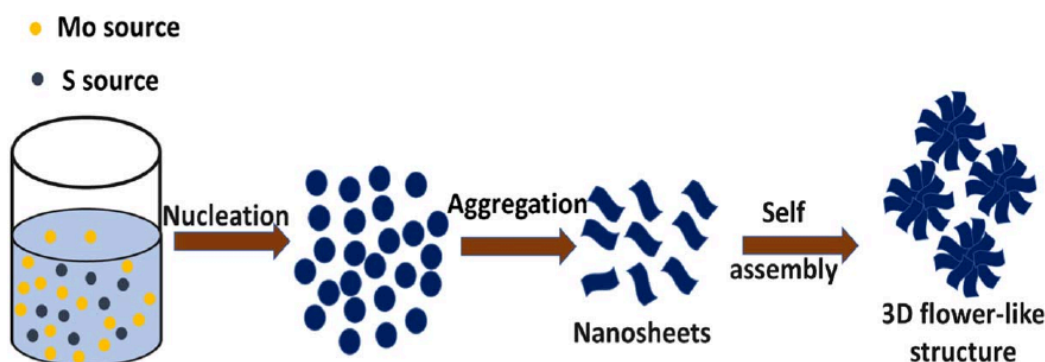


Figure 9. Growth mechanism of 3D flower-like MoS₂ nanostructures.

MoS₂ nanosheets has been proposed as shown schematically in Fig. 9. The growth process can be divided into three steps: (i) nucleation, (ii) aggregation in nanosheets, and (iii) self-assembly of nanosheets resulting in the formation of nanoflowers. Initially in the presence of water, Mo [(NH₄)₆Mo₇O₂₄·4H₂O] and S [CH₄N₂S] sources collide elastically and form a transparent homogeneous solution at room temperature. In the next step, the hydrothermal process generates H₂S gas by hydrolysis of thiourea, which creates high pressure leading to the formation of MoS₂ nuclei. These MoS₂ nuclei grow over time and form S-Mo-S layers. It is worth noting that hydrothermal temperature should be between the boiling point and critical temperature of water. Thereafter, the aggregation of primary MoS₂ nuclei due to high stress leads to the formation of nanosheets. These nanosheets form the basis for the formation of nanoflowers via the self-assembly process. Furthermore, as the hydrothermal temperature is increased, the nuclei begin to form bigger in size resulting in better quality of crystal of MoS₂ nanoflowers, as indicated by the structural and morphological analysis. This is because the critical nuclei size increases with an increase in temperature and the barrier for nucleation is greater with increasing temperature. Therefore, an increase in temperature hinders the initiations of nucleation for new nuclei, and as a result, the earlier formed nuclei begin to increase in size.⁶⁸ However, when synthesis time is increased beyond a typical value (here it is 24 h), the morphology of 3D flower-like nanostructures becomes uneven due to the effect of high stress for longer duration, as evident by the Fig. 7e.

Conclusions

The 3D flower-like MoS₂ nanostructures were successfully synthesized via a facile hydrothermal method at diverse temperatures and times. This 3D flower-like morphology of MoS₂ nanostructure was found to be formed due to a nucleation-oriented self-assembly growth process. The influence of reaction temperature and

Author Contributions

R. Kumari carried out the experimental research work towards synthesis and characterization of MoS₂ nanostructures. The present study was conceived and supervised by R. Kumar, Assistant Professor, Department of Physics and Astrophysics, Central University of Haryana, Mahendragarh, India.

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Data Availability

The authors declare that the data supporting the findings of this study are available within the article. Complementary data relevant for the present study are available from the corresponding author upon reasonable request.

Competing Interest

The authors have no relevant financial or non-financial interests to disclose.

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interplanar spacing, fewer defects, and a uniform flower-like morphology. The results of this study strongly suggest that the reaction temperature and duration for the synthesis of MoS₂ nanostructures play an important role. These findings propose the future use of MoS₂ nanostructures in different applications, including gas and biosensing, energy storage and conversion, as well as photocatalyst for hydrogen evolution reaction and degradation of organic pollutants.

Acknowledgments

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... Heterojunctions spatially separate electron-hole pairs via built-in electric fields at the interface, and extend light absorption, enhance specific surface area, and increase active site density [32,33]. MoS₂, characterized by its hexagonal-packed layered structure similar to graphene and its tunable band gap, exhibits versatile conductivity, ranging from n-type to p-type, depending on the presence of sulfur and molybdenum vacancies [34, 35]. Its two-dimensional (2D) nature and extensive surface area significantly enhance its photocatalytic performance [36]. ...

... Once the final product had been cooled to room temperature, it was subjected to several washes using deionized water and ethanol before being dried at a temperature of 60°C. Additionally, bare MoS₂ was synthesized under identical conditions, excluding the addition of SnS₂ nanostructures, following the methodology detailed in our previous study [34]. ...

... Two distinct excitonic peaks were found within the visible range. The peaks seen are a result of direct bandgap transitions that take place at the K points within the Brillouin zone [34, 65]. Figure 6(a) also demonstrates a distinct pattern in which the MoS₂/SnS₂ heterojunction sample exhibits a higher absorption of visible light as the MoS₂ nanostructures are loaded. ...

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In this study, 3D flower-like MoS₂ nanostructures were synthesized using a hydrothermal technique to form heterostructures with 2D porous SnS₂ nanosheets. The resulting 3D/2D MoS₂/SnS₂ heterostructures were evaluated for their photocatalytic abilities in removing Cr (VI), tetracycline (TC), and methylene blue (MB) under simulated solar irradiation. The results demonstrate that the MoS₂/SnS₂ ... [\[Show full abstract\]](#)

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